

Features :

- Interdigitated amplifying gates
- Fast turn-on and high di/dt
- Low switching losses
- Short turn-off time
- Hermetic metal cases with ceramic insulators

$I_{T(AV)}$ **1340A**
 V_{DRM}/V_{RRM} **1100~1400V**
 t_q **15~28μs**
 I_{TSM} **18kA**

Typical Applications

- Inductive heating
- Electronic welders
- Self-commutated inverters
- AC motor speed control
- General power switching applications



SYMBOL	CHARACTERISTIC	TEST CONDITIONS	$T_j(^{\circ}C)$	VALUE			UNIT
				Min	Type	Max	
$I_{T(AV)}$	Mean on-state current	180° half sine wave 50Hz Double side cooled,	125			1340	A
V_{DRM} V_{RRM}	Repetitive peak off-state voltage Repetitive peak reverse voltage	tp=10ms	125	1100		1400	V
I_{DRM} I_{RRM}	Repetitive peak off-state current Repetitive peak reverse current	at V_{DRM} at V_{RRM}	125			80	mA
$I_{T(f)}$	High frequency on-state current	F=6KHz, $T_c=55^{\circ}C$				800	A
I_{TSM}	Surge on-state current	10ms half sine wave $V_R=0.6V_{RRM}$	125			18	kA
I^2t	I^2T for fusing coordination					1620	$A^2s \times 10^3$
V_{TO}	Threshold voltage		125			1.60	V
r_T	On-state slop resistance					0.31	$m\Omega$
V_{TM}	Peak on-state voltage	$I_{TM}=2400A$, F=24kN	125			2.34	V
dv/dt	Critical rate of rise of off-state voltage	$V_{DM}=0.67V_{DRM}$	125			200	$V/\mu s$
di/dt	Critical rate of rise of on-state current	$V_{DM}=67\%V_{DRM}$, to 2000A Gate pulse $t_r \leq 0.5\mu s$ $I_{GM}=1.5A$	125			1500	$A/\mu s$
Q_{rr}	Recovery charge	$I_{TM}=1000A$, tp=2000μs, $di/dt=-60A/\mu s$, $V_R=50V$	125		87		μC
t_q	Circuit commutated turn-off time	$I_{TM}=1000A$, tp=2000μs, $V_R=50V$ $dv/dt=30V/\mu s$, $di/dt=-60A/\mu s$	125	15		28	μs
I_{GT}	Gate trigger current			30		250	mA
V_{GT}	Gate trigger voltage	$V_A=12V$, $I_A=1A$	25	0.8		3.0	V
I_H	Holding current			20		400	mA
V_{GD}	Non-trigger gate voltage	$V_{DM}=67\%V_{DRM}$	125	0.3			V
$R_{th(j-c)}$	Thermal resistance Junction to case	DC double side cooled Clamping force 24kN				0.020	$^{\circ}C/W$
$R_{th(c-h)}$	Thermal resistance case to heat sink					0.005	
F_m	Mounting force			19		26	kN
T_{stg}	Stored temperature			-40		140	°C
W_t	Weight				440		g
Outline		P11					

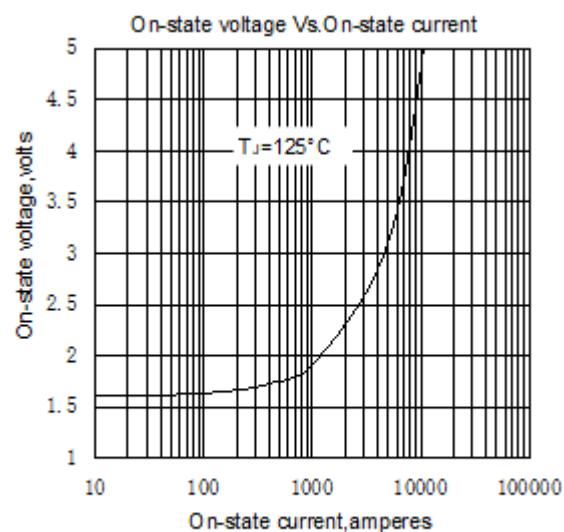


Fig. 1

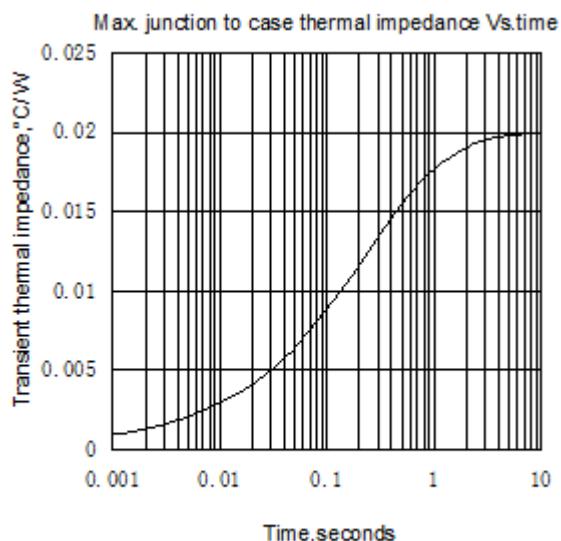


Fig. 2

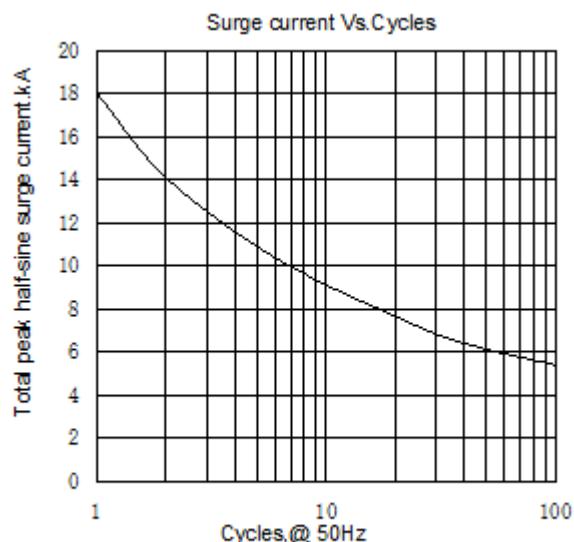


Fig. 3

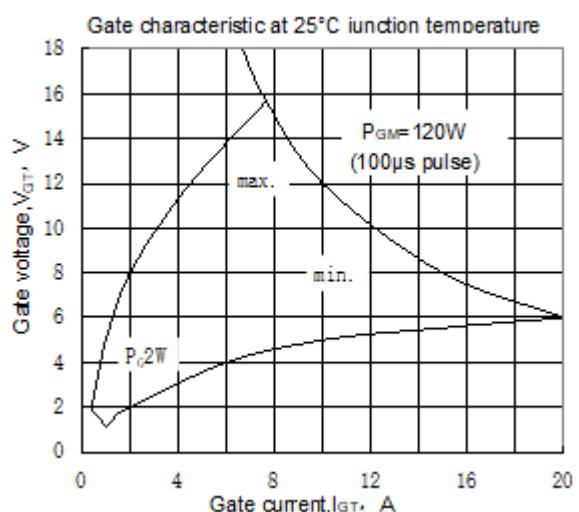


Fig. 4

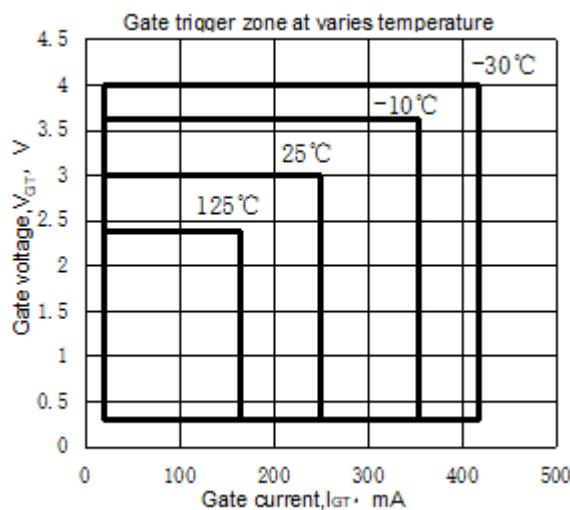


Fig. 5

